DECLARATION FOR PATENT APPLICATION AND POWER OF ATTORNEY

(Under 37 CFR § 1.63; includes reference to PCT International Applications)

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention ENTITLED:

CATALYST FOR DIMETHYL ETHER SYNTHESIS AND ITS PREPARATION METHODS

the specification of which:						
	PCT Application No. I	ion Serial No Continuation or CT/KR2004/0 S., and publishe	Continuation-in-Part or Divi 02174, filed <u>August 30, 2004</u> d as <u>WO2005/028104</u> on <u>Ma</u> plicable, give details).	<u> </u>		
	state that I have review		and the contents of the above ferred to above.	-identified spe	ecification,	
			d States Patent and Trademann Title 37, Code of Federal F			
I hereby claim foreign priority benefits under Title 35, United States Code § 119 of any foreign application(s) for patent or inventor's certificate or of any PCT International application(s) designating at least one country other than the United State of America listed below and have also identified below any foreign application for patent or inventor's certificate or any PCT International applications designating at least one country other than the United States of America filed by me on the same subject matter having a filing date before that of the application(s) on which priority is claimed:						
Prior Foreign/PCT Application(s) [list additional applications on separate page]:						
Country (or F KR	PCT) <u>Application</u> 10-2003-	n Number: 0065380	Filed (Day/Month/Year) 20 / September / 2003	Priority C <u>Yes</u> ⊠ □	laimed: No	
I hereby claim the benefit under 35 U.S.C. §119(e) of any United States application listed below:						
(Applica	ition Number)	(Filing Date)				
I hereby	claim the benefit under	r Title 35, Unite	d States Code § 120 of any U	Inited States a	pplication(s)	

or PCT international application(s) designating the United States of America that is/are listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in that/those prior application(s) in the manner provided by the first paragraph of Title 35, United States Code § 112, I acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:

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Prior U.S. (or U.S.-designating PCT) Application(s) [list additional applications on separate page]:

<u>U.S. Serial No.:</u> Filed (Day/Month/Year) PCT Application No. Status (patented, pending, abandoned)

		a full power of su erein, to file cont in the Patent and oer of the applica	, and Frommer La bstitution and revolution tinuation and divis Trademark Office ttion in the space p	ocation, to ional apparent in the orovided	to prosecu plications ne Courts above, an	te this ap thereof, the in connection d specify	pplication, to receive ction
Ror	nald R. Santucci						
	c/o FROMMER LAWRENCE & HAU 745 Fifth Avenue	G LLP	Direct all telephoto the attention of		to: (212)	588-080	0
	New York, NY 10151		Ronald R.	Sant	ucci		
	made on information and belief are beli knowledge that willful false statements under Section 1001 of Title 18 of the Uthe validity of the application or any part INVENTOR(S): Signature: Full name of sole or first inventor: Residence:	and the like so noted States Code tent issued thereof Jun, Ki-Won	nade are punishable and that such wion.	e by fine llful false Date:	e or imprise statement	onment, its may jo	or both, eopardize
	Citizenship:	305-333 Repu Korea	Apt., Jeonmin-c blic of Korea	iong, Yt	iseong-gu	, Daejeo	n,
	Signature: Roh HS			Date:	Feb.	10,	200 6
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	Signature:)		Date:	Feb.	20,	2006

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Residence:

Citizenship:

Signature:	Date: Feb 20, 2002
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